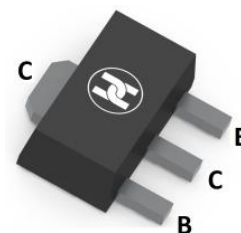
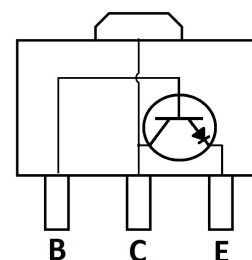


BIPOLAR TRANSISTOR (NPN)
FEATURES

- High Speed Switching Time
- Low Collector-emitter saturation voltage
- For Power Amplifier Application
- Surface Mount device


SOT-89

MECHANICAL DATA

- Case: SOT-89
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.055 grams (approximate)

MAXIMUM RATINGS ($T_A = 25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	2	A
Collector Power Dissipation	P_C	500	mW
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	250	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 ~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Collector-base breakdown voltage	$V_{(BR)CBO}$	50			V	$I_C=100\mu\text{A}$, $I_E=0$
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	50			V	$I_C=1\text{mA}$, $I_B=0$
Emitter-base breakdown voltage	$V_{(BR)EBO}$	5			V	$I_E=100\mu\text{A}$, $I_C=0$
Collector cut-off current	I_{CBO}			0.1	μA	$V_{CB}=50\text{V}$, $I_E=0$
Emitter cut-off current	I_{EBO}			0.1	μA	$V_{EB}=5\text{V}$, $I_C=0$
DC current gain	h_{FE1}	82		390		$V_{CE}=2\text{V}$, $I_C=0.5\text{A}$
	h_{FE2}^*	40				$V_{CE}=2\text{V}$, $I_C=2\text{A}$
Collector-emitter saturation voltage	$V_{CE(sat)}$			0.5	V	$I_C=1\text{A}$, $I_B=50\text{mA}$
Base-emitter saturation voltage	$V_{BE(sat)}$			1.2	V	$I_C=1\text{A}$, $I_B=50\text{mA}$
Transition frequency	f_T	150			MHz	$V_{CE}=2\text{V}$, $I_C=0.5\text{A}$, $f=100\text{MHz}$

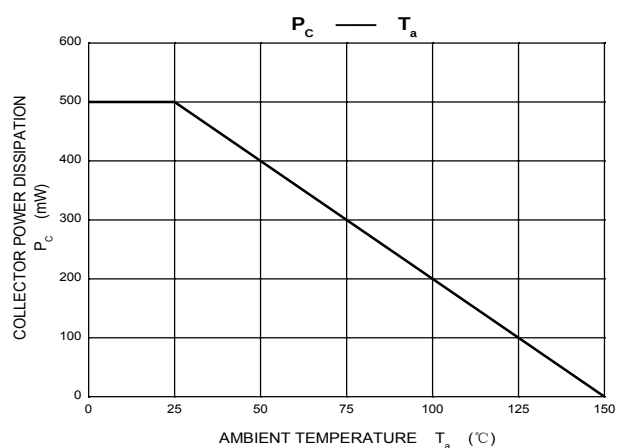
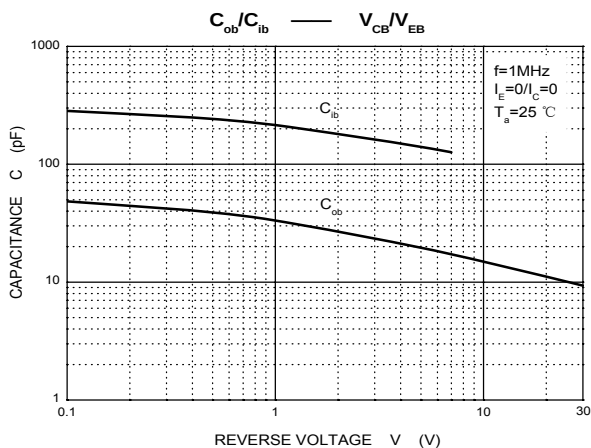
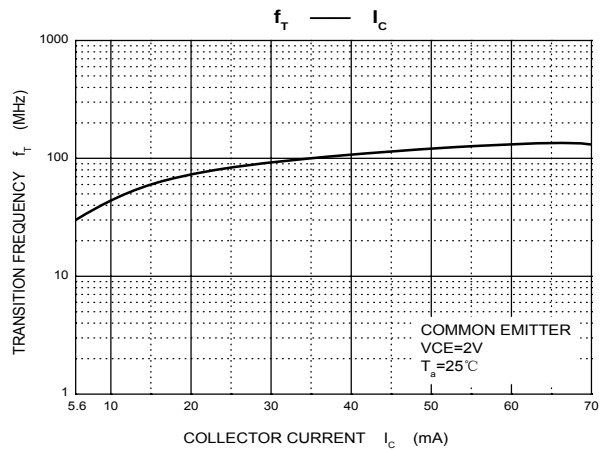
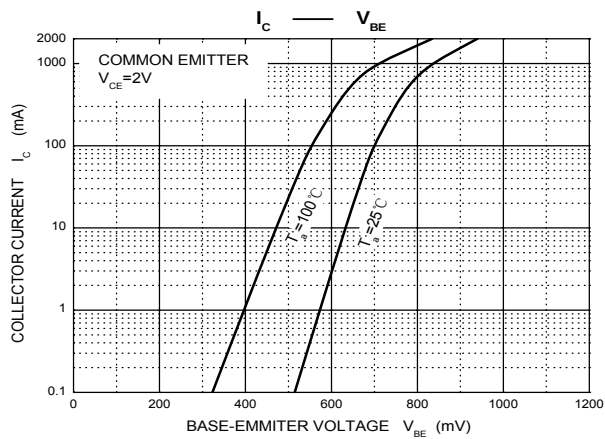
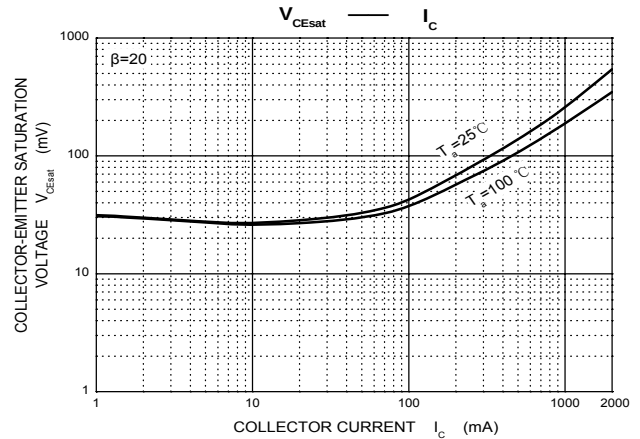
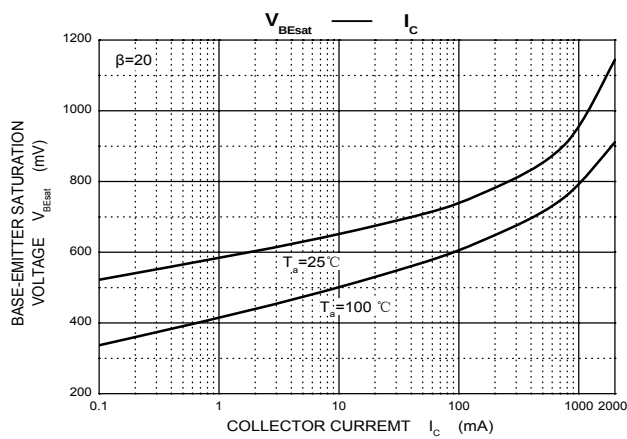
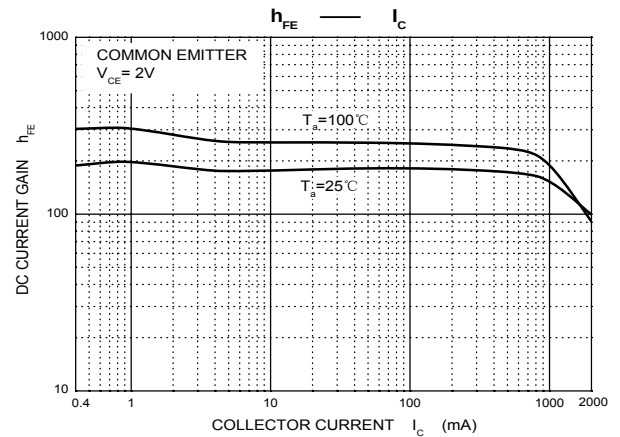
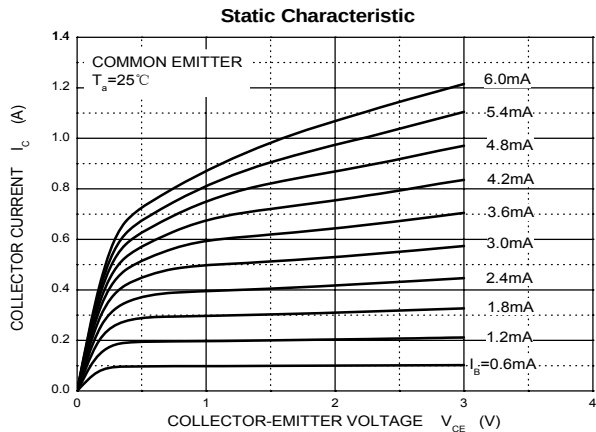
*Pulse test:pulse width $\leq 300\mu\text{s}$,duty cycle $\leq 2.0\%$

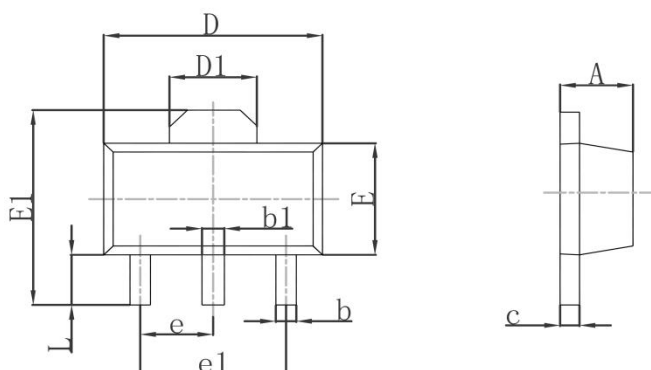
CLASSIFICATION OF h_{FE}

Rank	P	Q	Y
Range	82-180	120-270	180-390
Marking	P1766	Q1766	Y1766

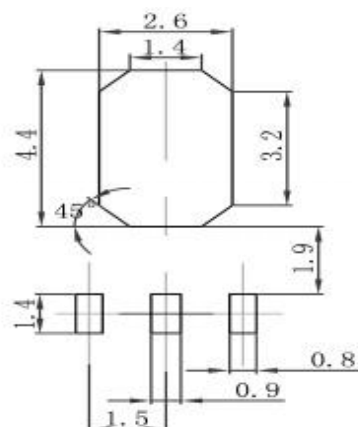
BIPOLAR TRANSISTOR (NPN)

Typical Characteristics



BIPOLAR TRANSISTOR (NPN)
SOT-89 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550REF		0.061REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500TYP		0.060TYP	
e1	3.000TYP		0.118TYP	
L	0.900	1.200	0.035	0.047

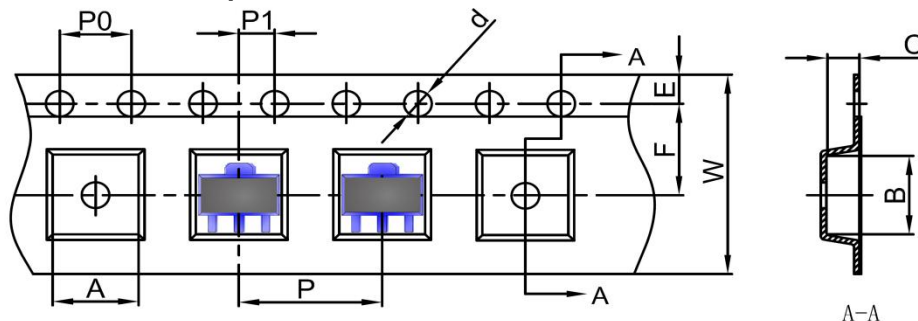
SOT-89 Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

BIPOLAR TRANSISTOR (NPN)

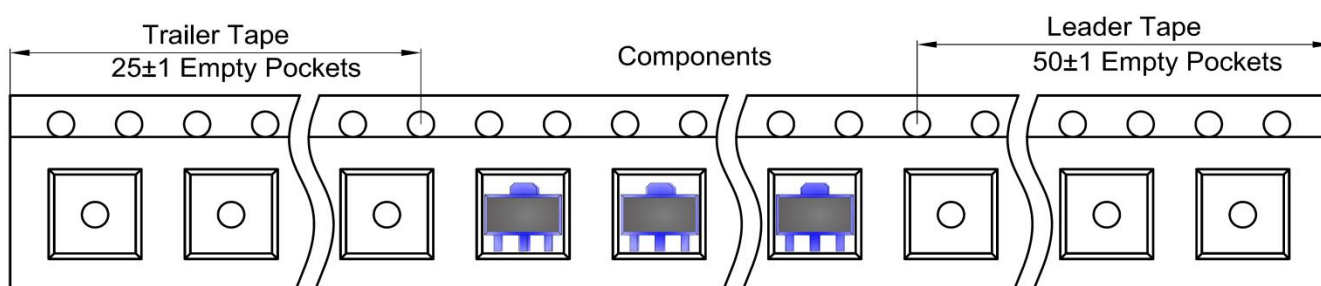
SOT-89 Tape and Reel

SOT-89 Embossed Carrier Tape

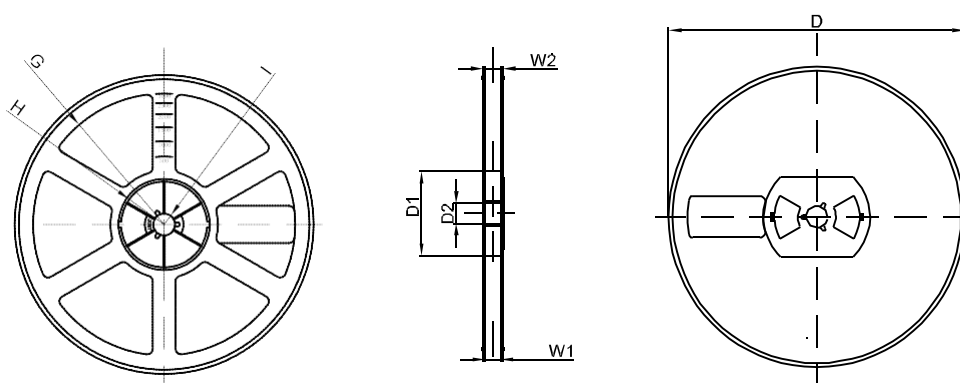


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-89	4.85	4.45	1.85	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-89 Tape Leader and Trailer



SOT-89 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	13.20	16.50
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1